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- State-of-the-Art BiCMOS Design Significantly Reduces I<sub>CCZ</sub>
- ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015
- Power-Up High-Impedance State
- 3-State Inverting Outputs
- Back-to-Back Registers for Storage
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK) and Flatpacks (W), and Plastic and Ceramic 300-mil DIPs (JT, NT)

#### description

The 'BCT544 octal registered transceiver contains two sets of D-type latches for temporary storage of data flowing in either direction. Separate latch-enable (LEAB or LEBA) and output-enable (OEAB or OEBA) inputs are provided for each register to permit independent control in either direction of data flow.

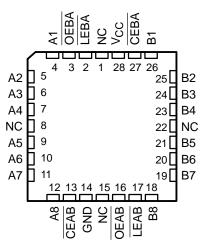
The A-to-B enable ( $\overline{CEAB}$ ) input must be low in order to enter data from A or to output data from B. If  $\overline{CEAB}$  is low and  $\overline{LEAB}$  is low, the A-to-B latches are transparent; a subsequent low-to-high transition of  $\overline{LEAB}$  puts the A latches in the storage mode. With  $\overline{CEAB}$  and  $\overline{OEAB}$  both low, the 3-state B outputs are active and reflect the inverted data present at the output of the A latches. Data flow from B to A is similar, but requires using the  $\overline{CEBA}$ ,  $\overline{LEBA}$ , and  $\overline{OEBA}$  inputs.

The SN54BCT544 is characterized for operation over the full military temperature range of  $-55^{\circ}$ C to 125°C. The SN74BCT544 is characterized for operation from 0°C to 70°C.

(Т	OP VIE	EW)	T PACKAGE
A1 [] A2 [] A3 [] A4 [] A5 [] A6 [] A7 [] A8 [] CEAB []	2 3 4 5 6 7 8 9 10 11	24 23 22 21 20 19 18 17 16 15 14 13	V <sub>CC</sub> CEBA B1 B2 B3 B4 B5 B6 B7 B8 LEAB OEAB

SN54BCT544 . . . JT OR W PACKAGE

#### SN54BCT544 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

# FUNCTION TABLE<sup>†</sup>

	INPU		OUTPUT	
CEAB	LEAB	OEAB	Α	В
Н	Х	Х	Х	Z
L	Х	н	х	Z
L	Н	L	Х	в <sub>0</sub> ‡
L	L	L	L	н
L	L	L	н	L

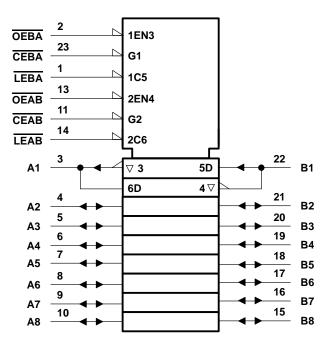
<sup>†</sup> A-to-B data flow is shown; B-to-A flow control is the same except that it uses CEBA, LEBA, and OEBA.

<sup>‡</sup>Output level before the indicated steady-state input conditions were established.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

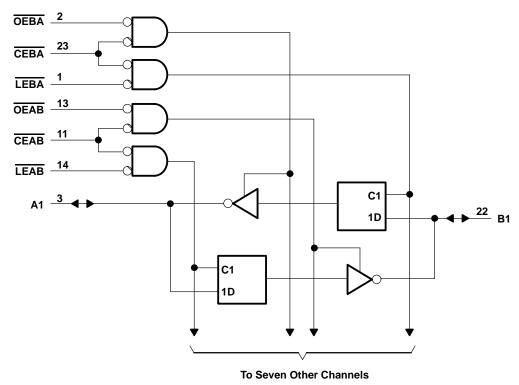
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### logic symbol<sup>†</sup>



<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

### logic diagram (positive logic)



Pin numbers shown are for the DW, JT, NT, and W packages.



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#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range, V <sub>CC</sub> Input voltage range: Control inputs (see Note 1)	
I/O ports (see Note 1)	– 0.5 V to 5.5 V
Voltage range applied to any output in the disabled or power-off state, $V_O$	– 0.5 V to 7 V
Voltage range applied to any output in the high state, VO	$\dots \dots \dots - 0.5$ V to V <sub>CC</sub>
Input clamp current	–30 mÅ
Current into any output in the low state: SN54BCT544	96 mA
SN74BCT544	128 mA
Operating free-air temperature range: SN54BCT544	– 55°C to 125°C
SN74BCT544	0°C to 70°C
Storage temperature range	– 65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input negative voltage rating may be exceeded if the input clamp-current rating is observed.

### recommended operating conditions

		SN54BCT544		SN74BCT544			UNIT	
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
$V_{IL}$	Low-level input voltage			0.8			0.8	V
Iк	Input clamp current			-18			-18	mA
IOH	High-level output current			-12			-15	mA
IOL	Low-level output current			48			64	mA
TA	Operating free-air temperature	-55		125	0		70	°C



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#### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		SN	54BCT5	44	SN74BCT544			UNIT
PARAMETER			MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT
VIK	V <sub>CC</sub> = 4.5 V,	lj = -18 mA			-1.2			-1.2	V
		$I_{OH} = -3 \text{ mA}$	2.4	3.3		2.4	3.3		
	V <sub>CC</sub> = 4.5 V	I <sub>OH</sub> = -12 mA	2	3.2					v
VOH		I <sub>OH</sub> = -15 mA				2	3.1		V
	V <sub>CC</sub> = 4.75 V,	I <sub>OH</sub> = –3 mA				2.7			
	V <sub>CC</sub> = 4.5 V	I <sub>OL</sub> = 48 mA		0.38	0.55				V
VOL		I <sub>OL</sub> = 64 mA					0.42	0.55	V
Ц	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 5.5 V			0.4			0.4	mA
IIH‡	V <sub>CC</sub> = 5.5 V,	VI = 2.7 V			20			20	μΑ
ι <sub>IL</sub> ‡	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 0.5 V			-0.6			-0.6	mA
I <sub>OS</sub> §	V <sub>CC</sub> = 5.5 V,	$V_{O} = 0$	-100		-225	-100		-225	mA
ІССН	V <sub>CC</sub> = 5.5 V			7	11		7	11	mA
ICCL	V <sub>CC</sub> = 5.5 V			43	68		43	68	mA
ICCZ	V <sub>CC</sub> = 5.5 V			9	15		9	15	mA
Ci	V <sub>CC</sub> = 5 V,	VI = 2.5 V or 0.5 V		6			6		pF
C <sub>io</sub>	V <sub>CC</sub> = 5 V,	V <sub>O</sub> = 2.5 V or 0.5 V		16			16		pF

<sup>†</sup> All typical values are at  $V_{CC}$  = 5 V,  $T_A$  = 25°C. <sup>‡</sup> For I/O ports, the parameters I<sub>IH</sub> and I<sub>IL</sub> include the off-state output current.

§ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

#### timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

			V <sub>CC</sub> = 5 V, T <sub>A</sub> = 25°C		SN54BCT544		SN74BCT544		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
tw	Pulse duration, LEAB or LEBA low		7		8		7		ns
t <sub>su</sub>	Setup time, data before $\overline{LEAB}$ or $\overline{LEBA}$	High or low	5		5.5		5		ns
<sup>t</sup> h	Hold time, data after $\overline{LEAB}$ or $\overline{LEBA}$	High or low	1		1		1		ns



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switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C<sub>L</sub> = 50 pF, R<sub>L</sub> = 500  $\Omega$  (unless otherwise noted) (see Note 2)

PARAMETER	FROM (INPUT)	то (оитрит)	V <sub>CC</sub> = 5 V, T <sub>A</sub> = 25°C		SN54BCT544		SN74BCT544		UNIT
	(INFOT)		MIN	MAX	MIN	MAX	MIN	MAX	
<sup>t</sup> PLH	A or B	Dari	2.4	7.6	2.4	10.3	2.4	9.7	
<sup>t</sup> PHL	A of B	B or A	3	7.6	3	8.9	3	8.5	ns
<sup>t</sup> PLH	LEBA	А	3.5	10.3	3.5	14.2	3.5	13.3	
<sup>t</sup> PHL		A	4.8	10.2	4.8	12.7	4.8	12.3	ns
<sup>t</sup> PLH	LEAB	В	3.5	10.3	3.5	14.4	3.5	13.4	
<sup>t</sup> PHL	LEAB	D	4.8	10.3	4.8	12.8	4.8	12.4	ns
<sup>t</sup> PZH		A or B	3	10.1	3	13.1	3	12.7	
<sup>t</sup> PZL	OE of CE	AUID	5.1	11.8	5.1	14.2	5.1	13.9	ns
<sup>t</sup> PHZ		A or B	2.8	7.5	2	8.9	2.8	8.5	
<sup>t</sup> PLZ		AUID	2.3	7.2	2.3	9	2.3	8.2	ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.



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